

Switching (300V, 16A)

2SK2739

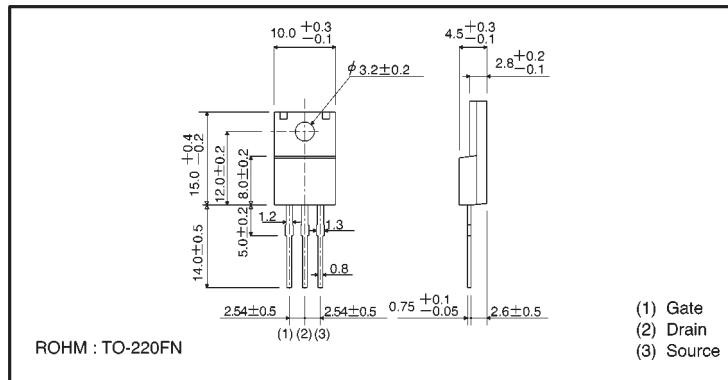
● Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Wide SOA (safe operating area).
- 4) Gate-source voltage (V_{GSS}) guaranteed to be $\pm 30V$.
- 5) Easily designed drive circuits.
- 6) Easy to use in parallel.

● Structure

Silicon N-channel
MOSFET

● External dimensions (Units: mm)



● Absolute maximum ratings ($T_a = 25^\circ C$)

Parameter	Symbol	Limits	Unit
Drain-source voltage	V_{DSS}	300	V
Gate-source voltage	V_{GSS}	± 30	V
Drain current	Continuous	I_D	A
	Pulsed	I_{DP}^*	A
Reverse drain current	Continuous	I_{DR}	A
	Pulsed	I_{DRP}^*	A
Total power dissipation ($T_c=25^\circ C$)	P_D	30	W
Channel temperature	T_{ch}	150	$^\circ C$
Storage temperature	T_{stg}	$-55 \sim +150$	$^\circ C$

* $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

● Packaging specifications

Type	Package	Bulk
	Code	—
	Basic ordering unit (pieces)	500
2SK2739		○

● Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Gate-source leakage	I_{GSS}	—	—	± 100	nA	$V_{GS} = \pm 30V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	300	—	—	V	$I_D = 1\text{mA}, V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	—	—	100	μA	$V_{DS} = 300V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(\text{th})}$	2.0	—	4.0	V	$V_{DS} = 10V, I_D = 1\text{mA}$
Static drain-source on-state resistance	$R_{DS(on)}$	—	0.27	0.33	Ω	$I_D = 8\text{A}, V_{GS} = 10V$
Forward transfer admittance	$ Y_{fs} ^*$	5.0	10	—	S	$I_D = 8\text{A}, V_{DS} = 10V$
Input capacitance	C_{iss}	—	1240	—	pF	$V_{DS} = 10V$
Output capacitance	C_{oss}	—	350	—	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	—	73	—	pF	$f = 1\text{MHz}$
Turn-on delay time	$t_{d(on)}$	—	19	—	ns	$I_D = 8\text{A}, V_{DD} = 100V$
Rise time	t_r	—	24	—	ns	$V_{GS} = 10V$
Turn-off delay time	$t_{d(off)}$	—	66	—	ns	$R_L = 12.5\Omega$
Fall time	t_f	—	22	—	ns	$R_G = 10\Omega$
Reverse recovery time	t_{rr}	—	230	—	ns	$I_{DR} = 16\text{A}, V_{GS} = 0V$
Reverse recovery charge	Q_{rr}	—	1.8	—	μC	$dI/dt = 100\text{A}/\mu\text{s}$

* $P_w \leq 300\ \mu\text{s}$, Duty cycle $\leq 1\%$

● Electrical characteristic curves

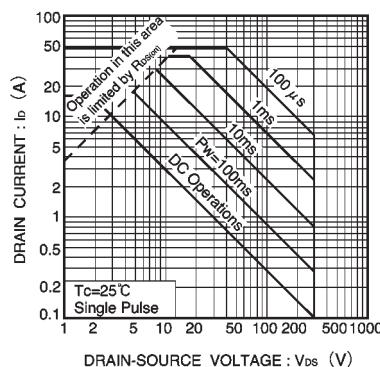


Fig.1 Maximum safe operating area

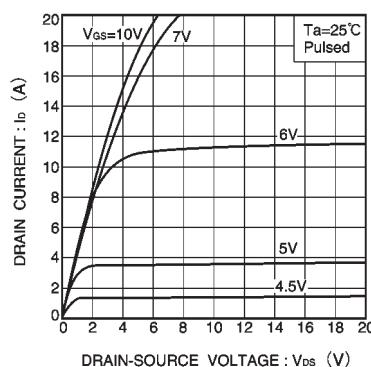


Fig.2 Typical output characteristics

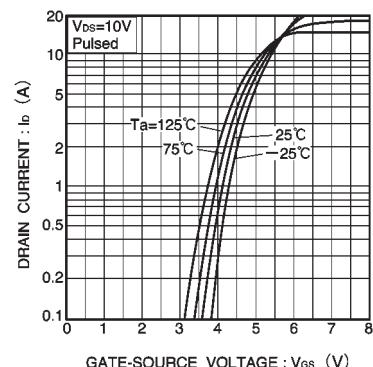
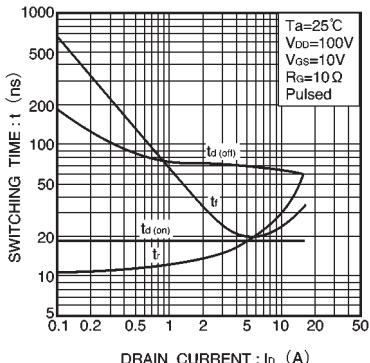
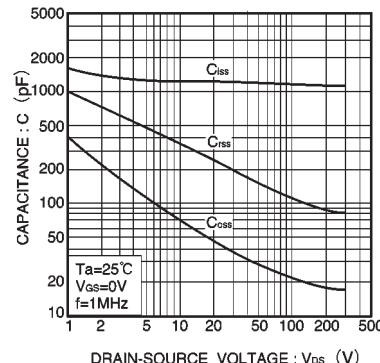
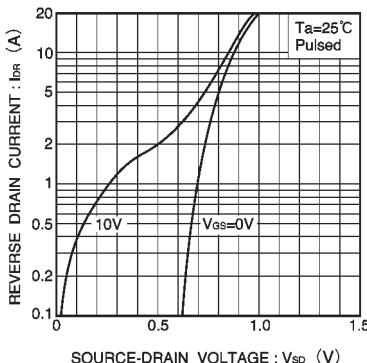
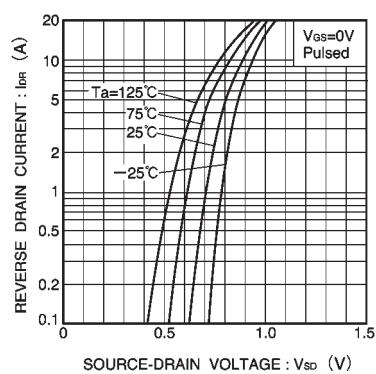
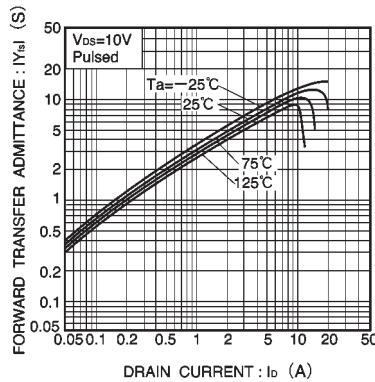
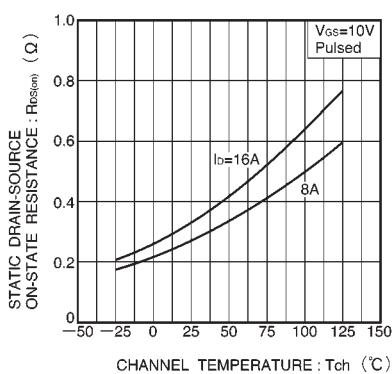
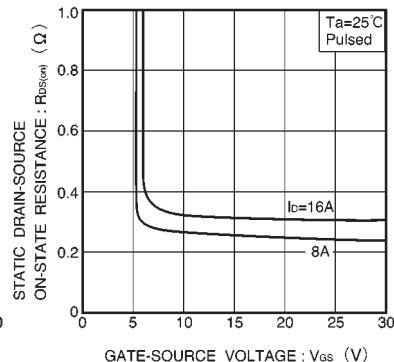
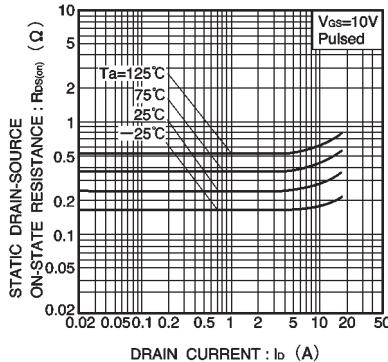
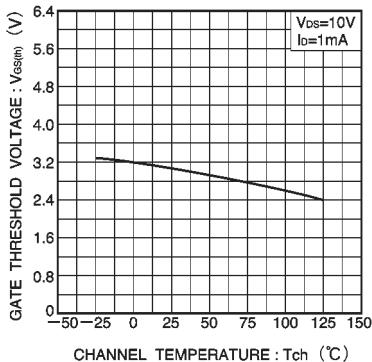
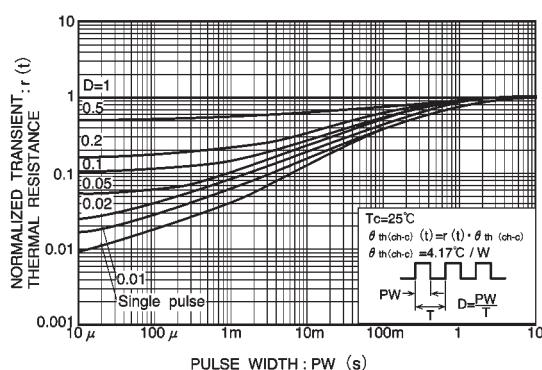
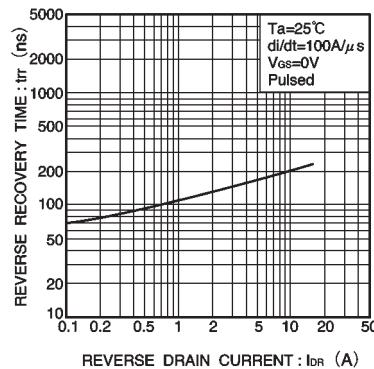
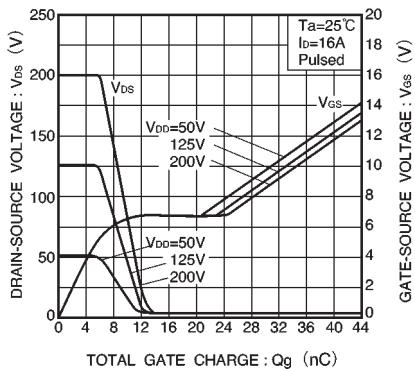


Fig.3 Typical transfer characteristics





● Switching characteristics measurement circuit

